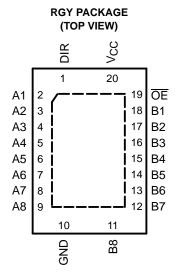
SCES271D-APRIL 1999-REVISED JULY 2004

#### **FEATURES**

- Operates from 1.65 V to 3.6 V
- Max t<sub>pd</sub> of 3.4 ns at 3.3 V

DGV, DW, NS, OR PW PACKAGE (TOP VIEW) DIR [ 20 V<sub>CC</sub> А1 П 19 \ OE A2 **∏** 18 T B1 3 А3 Г 17 П в2 16 ∏ B3 A4 **∏** 15 B4 A5 **∏** 6 14 N B5 А6 П A7 🛮 8 13**∏** B6 A8 🛮 9 12 B7 GND  $\Pi$ 10 11 B8

- ±24-mA Output Drive at 3.3 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17



#### **DESCRIPTION/ORDERING INFORMATION**

This octal bus transceiver is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The SN74ALVC245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable  $(\overline{OE})$  input can be used to disable the device so the buses are effectively isolated.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PAG	CKAGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
	QFN - RGY	Tape and reel	SN74ALVC245RGYR	VA245		
	SOIC - DW	Tube	SN74ALVC245DW	ALVC245		
	SOIC - DW	Tape and reel	SN74ALVC245DWR	ALVO245		
-40°C to 85°C	-40°C to 85°C SOP - NS		SN74ALVC245NSR	ALVC245		
	TCCOD DW	Tube	SN74ALVC245PW	VA245		
	TSSOP - PW	Tape and reel	SN74ALVC245PWR	── VA245		
	TVSOP - DGV	Tape and reel	SN74ALVC245DGVR	VA245		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



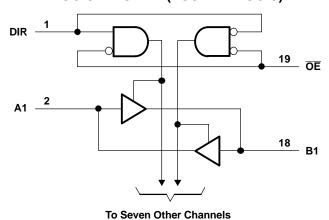
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### **FUNCTION TABLE**

INP	UTS	OPERATION					
ŌĒ	DIR	OPERATION					
L	L	B data to A bus					
L	Н	A data to B bus					
Н	X	Isolation					

### **LOGIC DIAGRAM (POSITIVE LOGIC)**



# **ABSOLUTE MAXIMUM RATINGS(1)**

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V	
.,	land valence recent	Except I/O ports <sup>(2)</sup>	-0.5	4.6		
V <sub>I</sub>	Input voltage range	I/O ports <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V	
Vo	Output voltage range <sup>(2)(3)</sup>	·	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA	
Io	Continuous output current			±50	mA	
	Continuous current through V <sub>CC</sub> or GND			±100	mA	
		DGV package <sup>(4)</sup>		92		
		DW package (4)		58		
$\theta_{JA}$	Package thermal impedance	NS package (4)		60	°C/W	
		PW package <sup>(4)</sup>		83		
		RGY package <sup>(5)</sup>		37		
T <sub>stg</sub>	Storage temperature range	•	-65	150	°C	

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

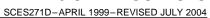
<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V, maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

<sup>5)</sup> The package thermal impedance is calculated in accordance with JESD 51-5.







# **RECOMMENDED OPERATING CONDITIONS**(1)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage		1.65	3.6	V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$			
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$		
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V		0.8		
V <sub>I</sub>	Input voltage	•	0	V <sub>cc</sub>	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 1.65 V		-4		
	High level autout avenue	V <sub>CC</sub> = 2.3 V		-12	mA	
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 2.7 V		-12		
	H High-level output current	V <sub>CC</sub> = 3 V		-24		
		V <sub>CC</sub> = 1.65 V		4		
	Lave lavel autout average	V <sub>CC</sub> = 2.3 V		12	A	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		12	mA	
		V <sub>CC</sub> = 3 V		24		
Δt/Δν	Input transition rise or fall rate	·		10	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
	$I_{OH} = -100 \mu A$	1.65 V to 3.6 V	V <sub>CC</sub> - 0.2			
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			
V <sub>OH</sub> V <sub>OL</sub> I  OZ <sup>(2)</sup> CC  ΔI <sub>CC</sub> C <sub>i</sub> Control inputs	I <sub>OH</sub> = -6 mA	2.3 V	2			
V <sub>OH</sub>	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V				
	I <sub>OH</sub> = -12 mA	2.7 V	2.2	,		
		3 V	30 3.6 V       V <sub>CC</sub> - 0.2         5 V       1.2         3 V       2         3 V       1.7         7 V       2.2         V       2.4         V       2         40 3.6 V       0.2         5 V       0.45         3 V       0.7         7 V       0.4         V       0.55         5 V       ±5         6 V       ±10         6 V       10         3 A       4.5			
	I <sub>OH</sub> = -24 mA	3 V	2		0.2 0.45 0.4 0.7 0.4 0.55 ±5	
	I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V			0.2	
V <sub>OL</sub>	I <sub>OL</sub> = 4 mA	1.65 V			0.45	
	I <sub>OL</sub> = 6 mA	2.3 V		,	0.4	\ /
	10 10	2.3 V			0.7	V
	I <sub>OL</sub> = 12 IIIA	2.7 V			0.4	
	I <sub>OL</sub> = 24 mA	3 V			0.55	
I <sub>I</sub>	$V_I = V_{CC}$ or GND	3.6 V			±5	μΑ
I <sub>OZ</sub> <sup>(2)</sup>	$V_O = V_{CC}$ or GND	3.6 V		,	±10	μΑ
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			10	μΑ
$\Delta I_{CC}$	One input at $V_{CC}$ - 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 3.6 V			750	μА
C <sub>i</sub> Control inputs	$V_I = V_{CC}$ or GND	3.3 V		4.5		pF
C <sub>io</sub> A or B ports	$V_O = V_{CC}$ or GND	3.3 V		11.5		pF

# **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1 ± 0.15	1.8 V 5 V	V <sub>CC</sub> = 2 ± 0.2	2.5 V ? V	V <sub>CC</sub> = 2	2.7 V	V <sub>CC</sub> = 3 ± 0.3	3.3 V 5 V	UNIT
	(INFOT)	(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	B or A	1.5	6	1	3.5		3.6	1.3	3.4	ns
t <sub>en</sub>	ŌĒ	A or B	3.4	8.6	2	6		6.3	1.6	5.5	ns
t <sub>dis</sub>	ŌĒ	A or B	2.7	8	1	4.8		5.3	1.7	5.5	ns

### **OPERATING CHARACTERISTICS**

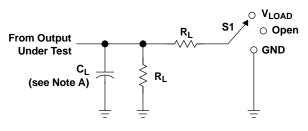
 $T_A = 25^{\circ}C$ 

PARAMETE	R	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT	
Power dissipation	Outputs enabled	C _ 0 pE f _ 10 MHz	25	27	30	pF	
capacitance per transceiver	Outputs disabled	$C_L = 0 \text{ pF, f} = 10 \text{ MHz}$	0	0	0	рF	

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. (2) For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.



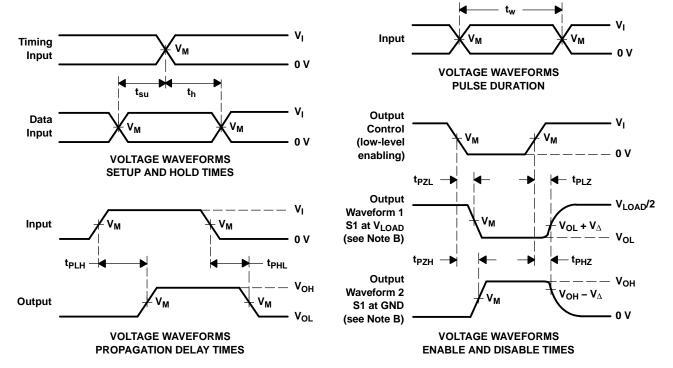
### PARAMETER MEASUREMENT INFORMATION



TEST	<b>S</b> 1
t <sub>pd</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

**LOAD CIRCUIT** 

V	IN	PUT	V	, , , , , , , , , , , , , , , , , , ,	•	В	, I
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	R <sub>L</sub>	$oldsymbol{V}_\Delta$
1.8 V ± 0.15 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{\Omega}$  = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





10-Jun-2014

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
SN74ALVC245DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA245	Samples
SN74ALVC245DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC245	Samples
SN74ALVC245DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC245	Samples
SN74ALVC245NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC245	Samples
SN74ALVC245PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA245	Samples
SN74ALVC245PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA245	Samples
SN74ALVC245PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA245	Samples
SN74ALVC245PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA245	Samples
SN74ALVC245PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA245	Samples
SN74ALVC245RGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	VA245	Samples
SN74ALVC245RGYRG4	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	VA245	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



# **PACKAGE OPTION ADDENDUM**

10-Jun-2014

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. **Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

- in homogeneous material)
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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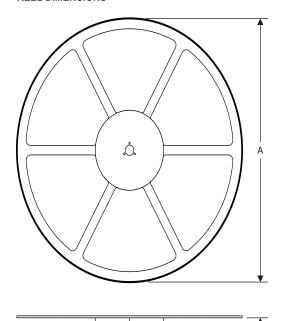
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# PACKAGE MATERIALS INFORMATION

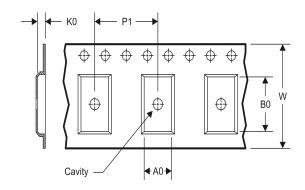
www.ti.com 14-Jul-2012

# TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**



#### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

\*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVC245DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74ALVC245DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74ALVC245NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74ALVC245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74ALVC245RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

www.ti.com 14-Jul-2012



\*All dimensions are nominal

All difficultions are normal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVC245DGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74ALVC245DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ALVC245NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74ALVC245PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74ALVC245RGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

# DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 DW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



# RGY (R-PVQFN-N20)

### PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-4/P 03/14

NOTE: All linear dimensions are in millimeters



# RGY (R-PVQFN-N20)

# PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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